

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	26	(carbon near nanotube near10 (monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:33
S2	132	(carbon near nanotube near10 (sensor or monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:33
S3	0	(carbon near nanotube near field near effect near transistor near10 (sensor or monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:33
S4	0	((carbon near nanotube near field near effect near transistor) near10 (sensor or monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:33
S5	0	((carbon near nanotube near field near effect near transistor) with (sensor or monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:33
S6	0	((carbon near nanotube near field near effect near transistor).clm. with (sensor or monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:34
S7	0	((carbon near nanotube near field near effect near transistor).clm. and (sensor or monitor or monitoring or monitored))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:34
S8	0	((carbon near nanotube near field near effect near transistor).clm. and (sensor or monitor or monitoring or monitored)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:34
S9	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm. and (sensor or monitor or monitoring or monitored)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:34

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S10	7	(cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:34
S11	5	(cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm. and (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:35
S12	5	(cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm. and (monitor or monitoring or monitored or sensor).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:36
S13	7	(cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:36
S14	5	(cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm. and (monitor or monitoring or monitored)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:37
S15	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm.) and (monitor or monitoring or monitored)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:37
S16	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm.) and (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:37
S17	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor)).clm.) and (monitor or monitoring or monitored or sensor).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:38
S18	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).clm. and (monitor or monitoring or monitored or sensor).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:38
S19	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).clm. with (monitor or monitoring or monitored or sensor).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:38

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S20	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).clm. with (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S21	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor)))with (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S22	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) with (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S23	0	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))) with (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S24	0	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))) same (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S25	9	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))) and (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S26	0	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).clm. and (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:39
S27	9	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))) and (monitor or monitoring or monitored or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:41
S28	5	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:42
S29	2	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).clm. and device. clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:43

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S30	19	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:43
S31	0	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).ti,ab,clm. and (monitor or monitoring or monitored or sensor).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:44
S32	5	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).ti,ab,clm. with transistor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:44
S33	5	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))).clm. with transistor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:45
S34	0	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))) with mosfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:45
S35	3	((cnt near fet) or ((carbon near nanotube near2 field near effect near transistor))) and mosfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:46
S36	2	"2003142679"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:47
S37	9	"6630772"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:47
S38	4	"6437329"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:48
S39	2	"20030218224"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 03:49

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S46	13	S44 and ((first or primary) near5 ((carbon adj nanotube) or (cnt near fet) or transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:47
S47	7	S44 and ((first or primary) near5 ((carbon adj nanotube) or (cnt near fet) or transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:50
S48	64960	((first or primary) near5 ((carbon adj nanotube) or (cnt near fet) or transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:50
S49	37649	((first or primary) near ((carbon adj nanotube) or (cnt near fet) or transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:50
S50	42	((first or primary) near ((carbon adj nanotube) or (cnt near fet) or transistor)).clm. and (carbon adj nanotube).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:50
S51	13	((first or primary) adj ((carbon adj nanotube) or (cnt near fet) or transistor)).clm. and (carbon adj nanotube).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:53
S52	0	((first or primary) adj ((carbon adj nanotube) or (cnt near fet) or transistor)).clm. and (carbon adj nanotube adj field).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:53
S53	0	((first or primary) adj ((carbon adj nanotube) or (cnt near fet) or transistor)).clm. and (carbon adj nanotube adj field)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:53
S54	9	((first or primary) adj ((carbon adj nanotube) or (cnt near fet) or transistor)) and (carbon adj nanotube adj field)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:54
S55	41629	((first or primary) adj ((carbon adj nanotube adj field adj effec adj transistor) or (cnt near fet) or transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:55

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S56	41632	((first or primary) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:55
S57	35610	((first or primary) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor)) and ((second) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:56
S58	34	((first or primary) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor)) and ((second) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor)) and (carbon adj nanotube)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:56
S59	0	((first or primary) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor)) and ((second) adj ((carbon adj nanotube adj field adj effect adj transistor) or (cnt near fet) or transistor)) and (carbon adj nanotube adj field)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 06:56
S60	0	((cnt near fet) or (carbon adj field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:01
S61	2	((cnt near fet) or (carbon adj nanotube adj field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:02
S62	12	((cnt near fet) or (carbon adj nanotube adj field adj effect adj transistor)).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:03
S63	36	((cnt near fet) or (carbon adj nanotube adj field adj effect adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:04

EAST Search History

S64	5	((plurality or multiple or two) near ((cnt near fet) or (carbon adj nanotube adj field adj effect adj transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:05
S65	8	((plurality or multiple or two or primary or secondary or second or first) near ((cnt near fet) or (carbon adj nanotube adj field adj effect adj transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:06
S66	10	((plurality or multiple or two or primary or secondary or second or first) near ((cnt near fet) or (carbon near2 nanotube near2 field near2 effect near2 transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:08
S67	3	((transistor or mosfet) near5 (cnt near fet))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:08
S68	3	((transistor or mosfet) near10 (cnt near fet))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:08

EAST Search History

S69	44	(US-20030068432-\$ or US-20020179434-\$ or US-20030089899-\$ or US-20050056826-\$ or US-20040224490-\$ or US-20030178617-\$ or US-20030170930-\$ or US-20040173378-\$ or US-20030218224-\$ or US-20010023986-\$ or US-20050059210-\$ or US-20040240252-\$ or US-20040214786-\$ or US-20040101685-\$ or US-20040079892-\$ or US-20040022943-\$ or US-20040016928-\$ or US-20030122133-\$ or US-20020030646-\$ or US-20050012163-\$).did. or (US-6852582-\$ or US-6445006-\$ or US-6630772-\$ or US-6722936-\$ or US-6769945-\$ or US-6780664-\$ or US-6787122-\$ or US-6841002-\$ or US-6841003-\$ or US-6777960-\$ or US-6720553-\$ or US-6437329-\$ or US-6848320-\$ or US-6645028-\$ or US-6730972-\$ or US-6465813-\$).did. or (JP-2003142679-\$).did. or (JP-2003142679-\$ or EP-989579-\$ or US-6437329-\$ or US-20030218224-\$ or US-20010023986-\$ or US-20030178617-\$ or DE-10032370-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	ON	2005/03/18 07:14
S70	21	S69 and (measure or measuring or measured or measurement)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:15
S71	6	S69 and (measure or measuring or measured or measurement).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:15
S72	1	S69 and 257/24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 07:39

EAST Search History

S73	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) with (detec or detecting or detected or detection) with (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:54
S74	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) with (detec or detecting or detected or detection or defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:55
S75	22	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) and (detec or detecting or detected or detection or defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:55
S76	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) same (detec or detecting or detected or detection or defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:55
S77	22	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) and (detec or detecting or detected or detection or defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:55
S78	11	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) and (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:55
S79	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).clm. and (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:55
S80	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).clm. and (defect or defective).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:56
S81	1	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).clm. and (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:56
S82	3	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).ti,ab,clm. and (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:57

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S83	4	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))).ti,ab,clm. and (detect or detecting or detected or detected or defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:57
S84	0	10/711083	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:57
S85	49	((cnt near fet) or ((carbon near nanotube near field near effect near transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:58
S86	0	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) and (defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:58
S87	11	((cnt near fet) or ((carbon near nanotube near field near effect near transistor))) and (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:58
S88	8015	(detect or detecting or detected or detection) near10 (defect or defective) near10 (circuit or circuitry)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 19:59
S89	8	(fet or (field adj effect adj transistor)) near10 (detect or detecting or detected or detection) near10 (defect or defective) near10 (circuit or circuitry)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 20:01
S90	4	(fet or (field adj effect adj transistor)) near5 (detect or detecting or detected or detection) near5 (defect or defective) near5 (circuit or circuitry)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/08 20:01
S91	11	(cnt near fet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:56
S92	0	10/711083	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:55

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S93	0	(cnt near fet) with stress	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:56
S94	141	(nanotube) with stress	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:57
S95	1697	(nanotube) with (mechanical or thermal or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:57
S96	1397	(carbon near nanotube) with (mechanical or thermal or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:57
S97	6	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) with (mechanical or thermal or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:58
S98	0	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) with (stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:58
S99	0	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) same (stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 18:59
S100	9	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) same (detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:01
S101	15	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) same (defective or sensor or sensed or sensing oor detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:01

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S10 2	15	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) same (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:01
S10 3	14	(carbon near nanotube near5 (fet or (field adj effect adj transistor))) with (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:03
S10 4	1382	(cnt or cntfet or (cnt near fet) or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) with (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:04
S10 5	14	((carbon near nanotube near5 (fet or (field adj effect adj transistor)))) with (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:04
S10 6	1382	(cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) with (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:04
S10 7	1046	(cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) near10 (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:04
S10 8	18	(cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) near10 (defective or sensor or sensed or sensing or detect or detecting or detected or detection or detector or stress or strain).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:05

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S109	0	(cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) near10 (stress or strain).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:05
S110	12	(cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) near10 (stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:05
S111	23	(cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) with (stress or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:05
S112	0	((cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) with (stress or strain)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:05
S113	23	((cnt or (carbon near nanotube near5 (fet or (field adj effect adj transistor)))) with (stress or strain))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:07
S114	25	"6630772"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:07
S115	33	"6630772" or "6437329" or "20030218224" or "20010023986"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:11
S116	11	S115 and (stress or defect or strain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:11
S117	11	S115 and (stress or defect or strain or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:11
S118	2	S115 and (stress or defect or strain or defective).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:12

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S119	11	S115 and (stress or defect or strain or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 19:12
S120	22108	(cnt or (carbon near nanotube) or (carbon near nano near tube))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:00
S121	127	(cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:01
S122	129	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))) or cntfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:03
S123	7	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))) or cntfet near10 (detect or detecting or detected or detection or detector or measure or measuring or measured or measurement)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:05
S124	12	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))) or cntfet near10 (detect or detecting or detected or detection or detector or measure or measuring or measured or measurement or sensor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:05
S125	12	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))) or cntfet near10 (detect or detecting or detected or detection or detector or measure or measuring or measured or measurement or sensor or sensing)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:06
S126	2	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))) or cntfet and (defective near (circuit or circuitry))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:12

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S12 7	30	"6630772"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:10
S12 8	5	"6437329"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:11
S12 9	2	"20030218224"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:12
S13 0	2	"20010023986"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:12
S13 1	127	(cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:13
S13 2	129	(cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor)) or cntfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:13
S13 3	127	(cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor)) or cntfet and (sensor or detector or detect or detecting or detected or detection)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:14
S13 4	62	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor)) or cntfet) and (sensor or detector or detect or detecting or detected or detection)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:14
S13 5	27	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor)) or cntfet) and (sensor or detector or detect or detecting or detected or detection) and (defect or defective)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:15

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S13 6	4	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor)) or cntfet) and (sensor or detector or detect or detecting or detected or detection) and (defect or defective) and defective	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 23:16
S13 7	4	((cnt or (carbon near nanotube) or (carbon near nano near tube)) near (fet or (field adj effect adj transistor)) or cntfet) and defective	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 06:34